

CLAIMS

What is claimed is:

1. An apparatus comprising:
a circuit substrate comprising a single crystal semiconductor layer having a smallest dimension reduced; and
circuit devices formed in the single crystal layer.
2. The apparatus of claim 1, wherein the circuit substrate is formed as part of a composite structure comprising a removable support substrate.
3. The apparatus of claim 2, wherein the junction between the single crystal semiconductor layer and the removable support structure is an oxide.
4. The apparatus of claim 1, wherein the circuit devices form integrated circuits that interact with other electrical devices off the single crystal layer.